



DEVICE NUMBER : DPT-255-030 REV : 1.2
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Phototransistor

PT5529B/L2

■ Features :

- Wide angle of half sensitivity $\theta = \pm 65^\circ$
- High sensitivity
- Fast response time
- Cutting Wavelength $\lambda_p = 840\text{nm}$

■ Description :

EVERLIGHT Dual Photo Transistor(PT5529B/L2) is a high speed and high sensitivity dual photo transistor in a flat side view plastic package.

The epoxy package spectrally matched to IR emitter ($\lambda_p = 940\text{nm}$)

■ Applications :

- Mouse
- Optoelectronic Switch

PART NO.	CHIP	LENS COLOR
	MATERIAL	
PT	Silicon	Black



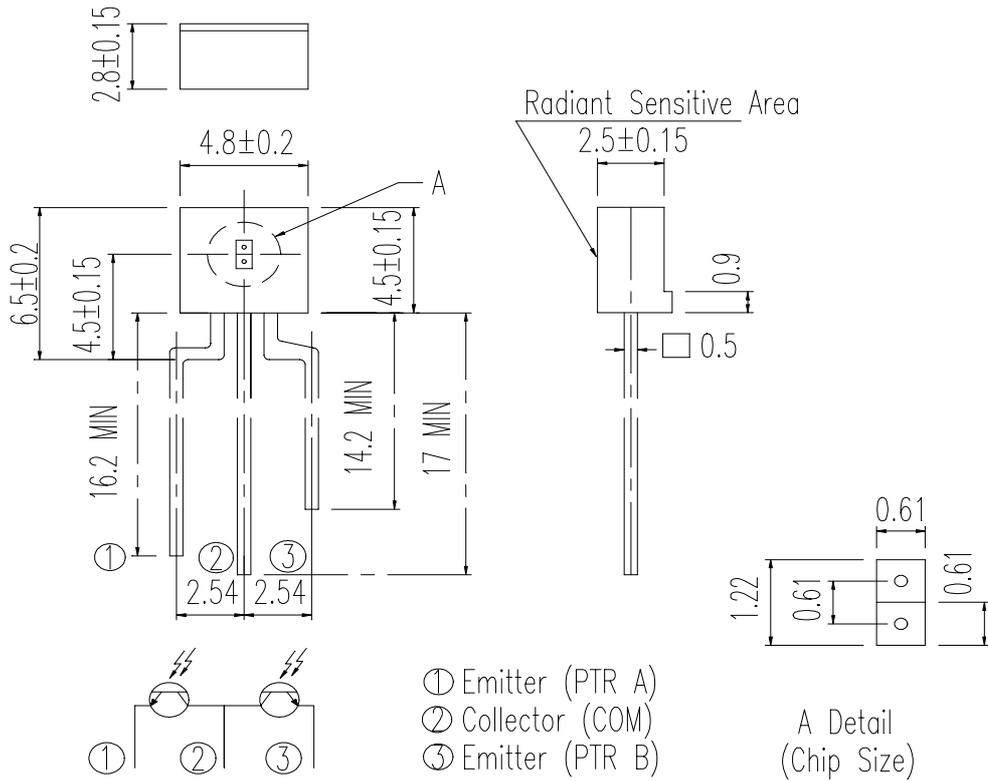
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Package Dimension :





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■ Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit	Notice
Collector power dissipation	P_d	75	mW	
C-E Voltage	V_{ce}	30	V	
E-C Voltage	V_{ec}	5	V	
Operating Temperature	T_{opr}	-25 ~ +85	$^\circ\text{C}$	
Storage Temperature	T_{stg}	-40 ~ +85	$^\circ\text{C}$	
Soldering Temperature (1/16 inch from body for 5 sec)	T_{sol}	260	$^\circ\text{C}$	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector dark current	I_{ceo}			100	nA	$V_{ce}=20\text{V}$, $E_e=0\text{mW}/\text{cm}^2$
C-E Saturation voltage	$V_{ce(sat.)}$			0.2	V	$I_C=2\text{mA}$, $I_B=100\mu\text{A}$
C-E Breakdown voltage	BV_{ceo}	30			V	$I_C=100\mu\text{A}$, $I_B=0$
E-C Breakdown voltage	BV_{eco}	5			V	$I_e=100\mu\text{A}$, $I_B=0$
On stat ecollector current	$I_C(\text{ON})$	129		944	μA	$E_e=0.555\text{mW}/\text{cm}^2$, $V_{ce}=5\text{V}$
Rise Time	t_r		15		μs	$V_{ce}=5\text{V}$ $I_C=1\text{mA}$ $R_L=1000\Omega$
Fall Time	t_f		15		μs	



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Typical Electrical/Optical/Characteristics Curves

Fig.1 Collector Power Dissipation vs. Ambient Temperature

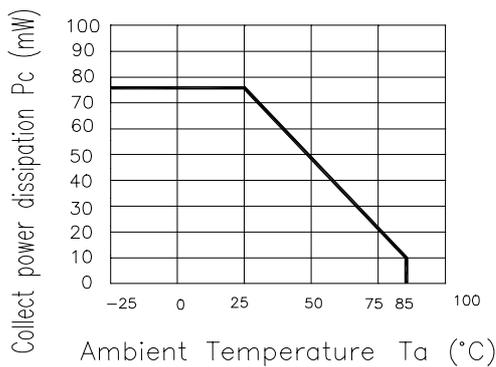


Fig.2 Collector Dark Current vs. Ambient Temperature

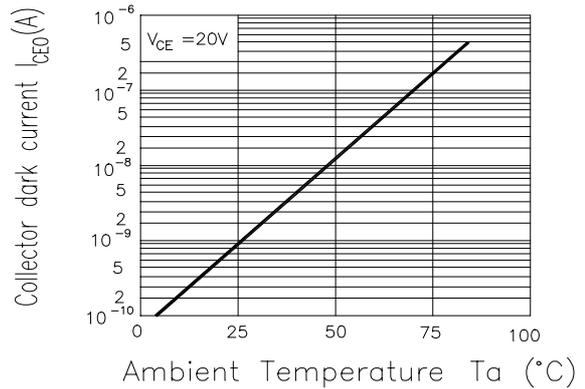


Fig. 3 Relative Collector Current vs. Ambient Temperature

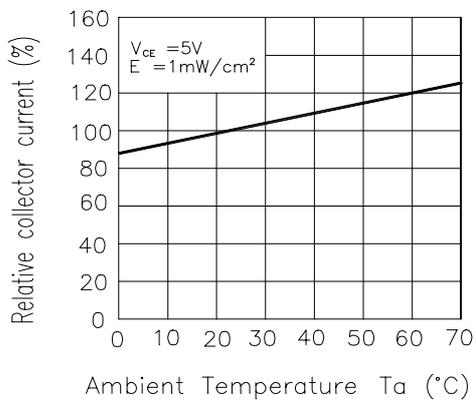


Fig.4 Collector Current vs. Irradiance

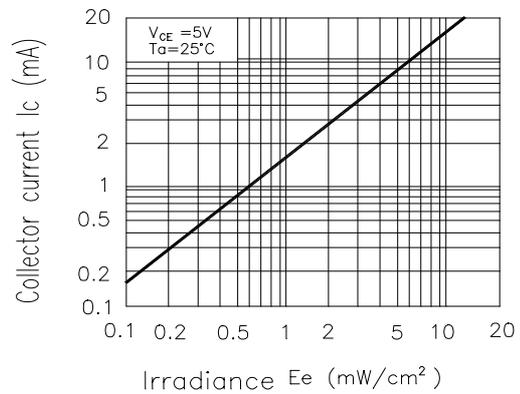


Fig.5 Spectral Sensitivity

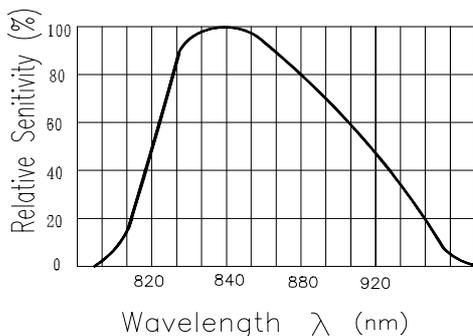
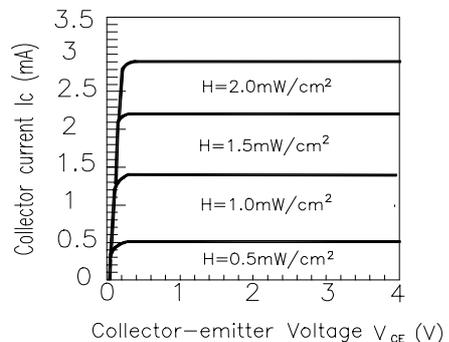


Fig.6 Collector Current vs. Collector-emitter Voltage





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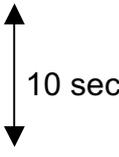
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■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level:90%

LTPD:10%

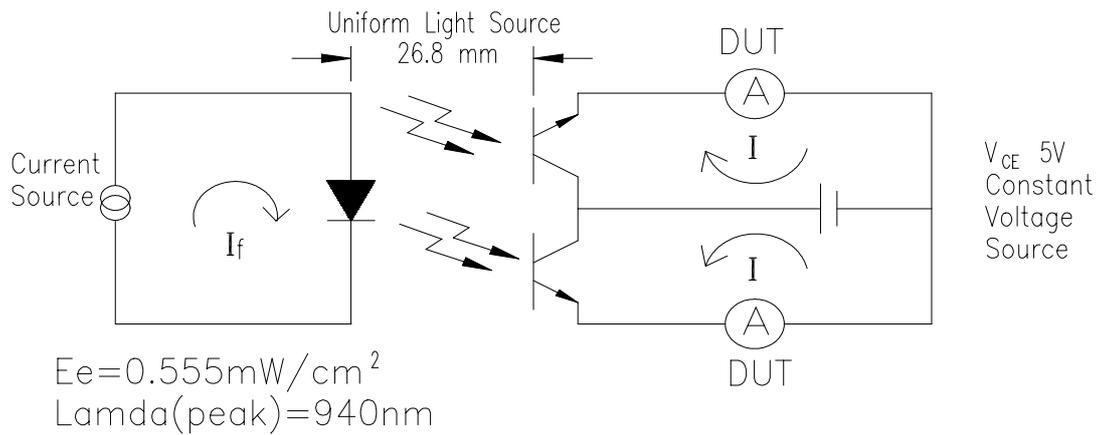
NO.	Item	Test Conditions	Test Hours/ Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solderability	TEMP : 230°C ± 5 °C	5 secs	22 PCs	More than 90% of lead to be covered by soldering	0/1
2	Temperature Cycle	H : +85°C 30 mins  L : -55°C 30 mins	50 cycles	22 PCs	$I_R \geq U \times 2$ $E_e \leq L \times 0.8$ $V_F \geq U \times 1.2$	0/1
3	Thermal Shock	H : +100°C 5 mins  L : -10°C 5 mins	50 cycles	22 PCs	U :Upper specification limit L :Lower specification limit	0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 PCs		0/1
5	Low Temperature Storage	TEMP. : -55°C	1000 hrs	22 PCs		0/1
6	DC Operating Life	$I_F = 20\text{mA}$	1000 hrs	22 PCs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 PCs		0/1

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Test Method :

The Light current testing method for PTR:



Ranking

Color Code	Parameter	Symbol	Min	Max	Unit	Test Condition
Red	A1	$I_{C(ON)}$	129	226	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
Blue	A2	$I_{C(ON)}$	195	306	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
Yellow	A3	$I_{C(ON)}$	262	380	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
Silver	A4	$I_{C(ON)}$	330	461	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
Green	A5	$I_{C(ON)}$	398	544	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
Purple	A6	$I_{C(ON)}$	468	625	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
White	A7	$I_{C(ON)}$	536	703	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
Brown	A8	$I_{C(ON)}$	604	785	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
Orange	A9	$I_{C(ON)}$	673	862	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$
Gold	A10	$I_{C(ON)}$	742	944	μA	$E_e = 0.555 \text{ mW/cm}^2$ $V_{CE} = 5V$



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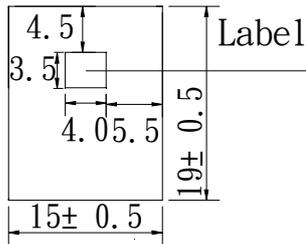
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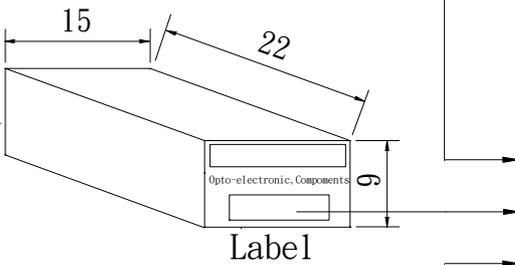
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■ Packing Specifications

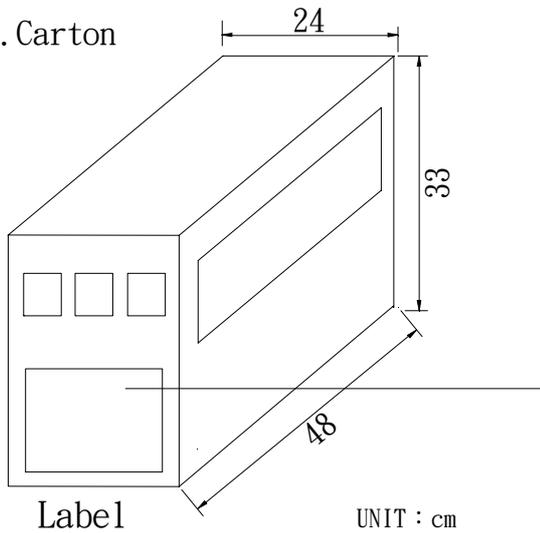
1. Bag



2. Box



3. Carton



CPN:

P/N: 3225591703



QTY:



CAT:

HUE:

REF:

LOT NO:

CPN : Customer's Production Number

P/N : Production Number

QTY : Packing Quantity

CAT : Ranks

HUE : Peak Wavelength

REF : Reference

LOT NO : Lot Number

■ Packing Quantity Specification

1. 500 Pcs / 1 Bag , 10 Bags / 1Box
2. 10 Boxess / 1Carton